DC N	Numbe	r.	20.	20230328008.2 PCN Date: March 30,									U 3 3
Title		l	w Assembl				Soloct	od Dovi	ico(c)	PCI	V Date.	Maich 30, 2	023
								eu Devi	. ,	- C			
Cust	omer Co	ontact:	PCN	-						lity Services ple requests Apr. 20, 2022*			
_		^t Ship Date			29, 2				acc		equests ed until:	Apr 29, 202	3*
		uests receiv	ed after Ap	or 29,	2023	will no	t be s	upporte	d.				
Char	nge Typ					I					1		
		bly Site			屵	Desig				<u> </u>		ump Material	
\boxtimes		bly Process			\vdash		Sheet		~ ~	屵	Wafer B	ump Process	
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		3, . 3, .			P		etail						
Desc	ription	of Change	:										
"Proc			n below. [re ma ir		rrent as			cility and	for devices lis piece part ch	
	Mount											Proposed	
		compound compound					458, 4 42096	211470 10				4147858 4211880	
	Mola	.ompound					42030	+0				4211000	
Reas	on for (Change:											
Cont	inuity of	supply.											
		impact on	Fit, Form,	, Fund	ction,	Quali	ity or	Reliabi	lity (p	osit	tive / ne	gative):	
None	<u>.</u>	<u> </u>					-				-		
Impa	act on E	nvironmer	ntal Rating	gs									
		es indicate t are checked										of this change gs.	e. If
		RoHS		REA	CH		G	reen S	tatus		IEC	62474	
	⊠ No C	Change	⊠ No	Chan	ige		⊠N	o Chan	ge		⊠ No Ch	nange	
Char	nges to	product ide	entificatio	n res	ulting	g fron	this	PCN:					
None	<u>.</u>												
Prod	luct Affe	ected:											
HVE	DA5405Q	HVDA542	QDRQ	1	MI	MLA00058DR			SN105099DR				
HVE	HVDA540QDRQ1 LBT-LM29					MI	MLA00058DRG4			SN65HVDA1050AQDR-M			1
	HVDA5415QDRQ1 LBT-LM2						MLA00151DR			ULQ2003ATDRRBG4			
	DA541QE							A00197DR					
	DA5425Q			KVZQDRQ1 MLA00197DRG4									
						•							

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Qualification Report

Approved 14-Mar-2023

Product Attributes

Attributes	Qual Device:	Qual Device:				
Attributes	MLA00197DRG4	SN65HVDA1050AQDR-M				
Automotive Grade Level	Grade 1	Grade 1				
Operating Temp Range (C)	-40 to 125	-40 to 125				
Product Function	Signal Chain	Signal Chain				
Wafer Fab Supplier	SH-BIP-1	DL-LIN				
Assembly Site	TAI	TAI				
Package Group	SOIC	SOIC				
Package Designator	D	D				
Pin Count	14	8				

QBS: Qual By Similarity

Qual Device MLA00197DRG4 is qualified at MSL3 260C

Qual Device SN65HVDA1050AQDR-M is qualified at MSL1 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: MLA00197DRG4	Qual Device: SN65HVDA1050AQDR- M		
Test G	oup A -	Accelerated Environment	Stress T	ests							
AC	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	3/231/0	3/231/0		
тс	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	3/231/0	3/231/0		
TC- BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	1/5/0	1/5/0		
HTSL	A6	A6 JEDEC JESD22-A103 1 45 High Temperature Storage Life 150C 1000 Hours		3/135/0	-						
Test G	Test Group B - Accelerated Lifetime Simulation Tests										
Test Group C - Package Assembly Integrity Tests											
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	3/90/0		
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	3/90/0		
SD	СЗ	JEDEC J-STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-	3/45/0	3/45/0		
PD	C4	JEDEC JESD22-B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	3/30/0	3/30/0		
Test G	oup D -	Die Fabrication Reliability	Tests								
EM	D1	JESD61	-	-	Electromigration	-	Completed Per - Technology Requirements		Completed Per Process Technology Requirements		
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		

ŀ	НСІ	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
1	NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
5	SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV:125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7 eV: 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Qualification Report

Approved 21-Sept-2021

Product Attributes

Attributes	Qual Device: CD4093BQM96Q1	Qual Device: K3HVD1781QDRQ1	Qual Device: <u>SE555DR</u>	Qual Device: SN103592DR	Qual Device: SN74HC S08QDRQ1	Qual Device: TCAN1043GDRQ1	Qual Device: TCAN1044VDRQ1	Qual Device: TLC5916QDRQ1	Qual Device: TMS3705DDRQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 3
Operating Temp Range	-40 to +125 C	-40 to +125 C	-55 to +125 C	-40 to +125 C	-40 to +125 C	-55 to +125 C	-40 to +125 C	-40 to +125 C	-40 to +85 C
Product Function	Signal Chain	Signal Chain	Signal Chain	Power Management	Signal Chain	Signal Chain	Signal Chain	Power Management	Logic
Wafer Fab Supplier	SH-BIP-1	DP1DM5	SH-BIP-1	SH-BIP-1	RFAB	MH8	RFAB	мн8	DL-LIN
Die Revision	-	-	В	С	B0	С	PG2.0	-	С
Assembly Site	FMX	MLA	TAI	TAI	MLA	FMX	MLA	FMX	TAI
Package Type	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC
Package Designator	D	D	D	D	D	D	D	D	D
Ball/Lead Count	14	8	8	8	14	14	8	16	16

⁻ QBS: Qual By Similarity

⁻ Qual Devices CD4093BQM96Q1, K3HVD1781QDRQ1, SE555DR, SN103592DR, SN74HCS08QDRQ1, TCAN1043GDRQ1, TCAN1044VDRQ1,TLC5916QDRQ1 are qualified at LEVEL1-260CG

⁻ Qual Device TMS3705DDRQ1 is qualified at LEVEL3-260CG

Qualification ResultsData Displayed as: Number of lots / Total sample size / Total failed

				L	Jala DIS	piaye	a as: Nu	mber of i	ots / rc	itaisan	nple size /	rotaria	illea		
Typ e	#	Test Spec	Mi n L ot Qt y	SS/L ot	Test Name / Condition onment Stres	Durati on	Qual Device: <u>CD4093BQ</u> <u>M96Q1</u>	Qual Device: <u>K3HVD1781Q</u> <u>DRQ1</u>	Qual Device: SE555DR	Qual Device: <u>SN103592</u> <u>DR</u>	Qual Device: <u>SN74HC S08Q</u> <u>DRQ1</u>	Qual Device: TCAN1043G DRQ1	Qual Device: <u>TCAN1044V</u> <u>DRQ1</u>	Qual Device: TLC5916Q DRQ1	Qual Device: TMS3705D DRQ1
Test G	oup		erate	G ENVII	onment sues	s resis									
AC	A 3	JEDE C JESD 22- A102	3	77	Autoclave 121C	96 Hours	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0
тс	A 4	JEDE C JESD 22- A104 and Appen dix 3	3	77	Temperatu re Cycle, - 65/150C	500 Cycle s	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0
PT C	A 5	JEDE C JESD 22- A105	1	45	Power Temperatu re Cycle	1000 Cycle s	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
Test G	roup	B – Acce	lerate	ed Lifeti	me Simulatio	n Tests									
ED R	B 3	AEC Q100- 005	3	77	NVM Endurance , Data Retention, and Operationa I Life	-	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
Test	Grou	p C – Pac	ckage	Assem	bly Integrity	Tests									
WB S	C 1	AEC Q100- 001	1	30	Wire Bond Shear (Cpk>1.67)	-	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0
WB P	C 2	MIL- STD8 83 Metho	1	30	Wire Bond Pull (Cpk>1.67)	-	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0
	T	d													
SD	C 3	2011 JEDE C JESD 22- B102	1	15	Surface Mount Solderabilit y >95% Lead Coverage	PB- Free Solder	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0
PD	C 4	JEDE C JESD 22- B100 and B108	3	10	Physical Dimension s (Cpk>1.67)	-	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0
SB S	C 5	AEC Q100- 010	3	50	Solder Ball Shear (Cpk>1.67)	Solder Balls	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
LI	C 6	JEDE C JESD 22- B105	1	50	Lead Fatigue	Leads	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0
LI	C 6	JEDE C JESD 22- B105	1	50	Lead Pull	Leads	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0
Tes	t Gro	up D – Di	ie Fat	orication	n Reliability T	ests									
EM	D 1	JESD 61	-	-	Electromigr ation	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
TD DB	D 2	JESD 35	-	-	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy	Complete d Per Process Technolo gy	Completed Per Process Technology Requirement s	Completed Per Process Technology	Completed Per Process Technology	Complete d Per Process Technolog y	Completed Per Process Technolog y

Typ e	#	Test Spec	Mi n L ot Qt y	SS/L ot	Test Name / Condition	Durati on	Qual Device: <u>CD4093BQ</u> <u>M96Q1</u>	Qual Device: <u>K3HVD1781Q</u> <u>DRQ1</u>	Qual Device: <u>SE555DR</u>	Qual Device: <u>SN103592</u> <u>DR</u>	Qual Device: SN74HC S08Q DRQ1	Qual Device: <u>TCAN1043G</u> <u>DRQ1</u>	Qual Device: <u>TCAN1044V</u> <u>DRQ1</u>	Qual Device: <u>TLC5916Q</u> <u>DRQ1</u>	Qual Device: <u>TMS3705D</u> <u>DRQ1</u>
							Requireme nts		Requirem ents	Requirem ents		Requireme nts	Requireme nts	Requirem ents	Requirem ents
нсі	D 3	JESD 60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
NB TI	D 4	1	1	1	Negative Bias Temperatu re Instability	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
SM	D 5	-	-	-	Stress Migration	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40° C to $+150^{\circ}$ C Grade 1 (or Q): -40° C to $+125^{\circ}$ C Grade 2 (or T): -40° C to $+105^{\circ}$ C Grade 3 (or I): -40° C to $+85^{\circ}$ C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

ZVEI reference ID: SEM-PA-07, SEM-PA-11

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail					
WW PCN Team	PCN ww admin team@list.ti.com					

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